



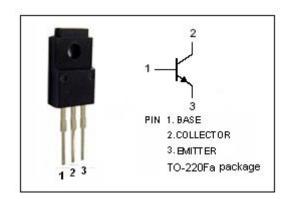
isc Silicon NPN Power Transistor

DESCRIPTION

- · Collector-Base Breakdown Voltage-
 - : V_{(BR)CBO}= 500V(Min.)
- · Low Collector Saturation Voltage
- · Wide Area of Safe Operation
- · High Speed Switching
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

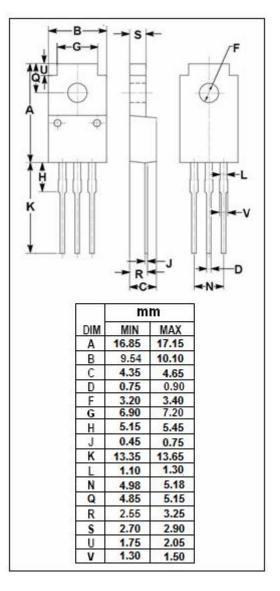


Designed for high speed switching applications.



ABSOLUTE MAXIMUM RATINGS (Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V _{СВО}	Collector-Base Voltage	500	V
V _{CES}	Collector-Emitter Voltage	500	V
V _{CEO}	Collector-Emitter Voltage	400	V
V _{EBO}	Emitter-Base Voltage	7	V
Ic	Collector Current-Continuous	1.5	А
Ісм	Collector Current-Peak	3	А
I _B	Base Current-Continuous	0.5	А
Pc	Collector Power Dissipation @T _a =25℃	2 W	
	Collector Power Dissipation @T _C =25°C	25	VV
T _j	Junction Temperature	150	$^{\circ}$ C
T _{stg}	Storage Temperature Range	-55~150	$^{\circ}$ C





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2SC3868

ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT		
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	I _C = 10mA; I _B = 0	400			٧		
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 0.8A; I _B = 0.16A			1.0	٧		
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	I _C = 0.8A; I _B = 0.16A			1.5	V		
Ісво	Collector Cutoff Current	V _{CB} = 500V; I _E = 0			100	μ A		
ІЕВО	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0			100	μ A		
h _{FE-1}	DC Current Gain	I _C = 0.1A; V _{CE} = 5V	15					
h _{FE-2}	DC Current Gain	I _C = 0.8A; V _{CE} = 5V	8					
f⊤	Current-Gain—Bandwidth Product	Ic= 0.2A; V _{CE} = 10V; f= 1MHz		25		MHz		
Switching T	īmes							
ton	Turn-on Time				0.7	μS		
ts	Storage Time	I _C = 0.8A; I _{B1} = 0.16A; I _{B2} = -0.32A; V _{CC} = 150V			2.0	μS		
t _f	Fall Time				0.3	μ s		

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